# NSN 5962-01-430-2124

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View Online at https://aerobasegroup.com/nsn/5962-01-430-2124

#### **Body Length:**

Between 1.270 inches and 1.290 inches

#### Body Width:

Between 0.300 inches and 0.320 inches

#### **Body Height:**

Between 0.190 inches and 0.210 inches

#### **Maximum Power Dissipation Rating:**

650.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### End Application:

Pacer dawn

#### Features Provided:

Erasable and programmed and ultraviolet erasable and electrostatic sensitive

#### Inclosure Material:

Ceramic

#### **Inclosure Configuration:**

Dual-in-line

#### Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

22 input

#### Criticality Code Justification:

Cbbl

#### Case Outline Source And Designator:

D-9 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Product Name:

Microcircuit, programmed

#### Voltage Rating And Type Per Characteristic:

-2.0 volts total supply and 7.0 volts total supply

#### **Time Rating Per Chacteristic:**

55.00 nanoseconds access

#### Memory Device Type:

Pal

#### **Special Features:**

Altered item programmed using 67268/5962-86864011x using firmware/version description document fdd/vdd 0249-01.00

### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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### Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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